

## Features

- Attenuation: 1.0 dB Steps to 31 dB
- Low DC Power Consumption
- Plastic SOW, Wide Body, SMT Package
- Integral TTL Driver
- 50 ohm Impedance
- Test Boards are Available
- Tape and Reel Packaging Available
- Lead-Free SOW-16 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS\* Compliant Version of AT65-0263

## Description

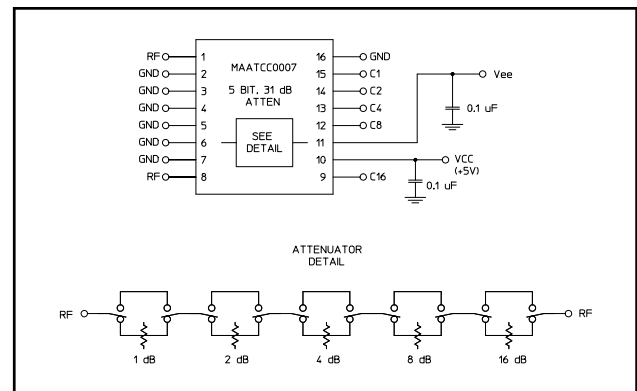
M/A-COM's MAATCC0007 is a GaAs FET 5-bit digital attenuator with integral TTL driver. Step size is 1.0 dB providing 31 dB total attenuation range. This device is in a SOW-16 plastic surface mount package. The MAATCC0007 is ideally suited for use where accuracy, fast speed, very low power consumption and low costs are required.

## Ordering Information

Part Number	Package
MAATCC0007	Bulk Packaging
MAATCC0007TR	1000 piece reel
MAATCC0007-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

## Schematic with Off-Chip Components



## Pin Configuration

Pin No.	Function	Pin No.	Function
1	RF	9	C16
2	GND	10	Vcc
3	GND	11	Vee
4	GND	12	C8
5	GND	13	C4
6	GND	14	C2
7	GND	15	C1
8	RF	16	GND

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

## Electrical Specifications: $T_A = 25^\circ\text{C}$

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	DC-2.0 GHz	dB	—	2.8	3.2
Attenuation Accuracy	Individual Bits 1-2-4-8-16 Any Combination of bits 3 - 29 dB Any Combination of bits 30 - 31 dB	DC-2.0 GHz DC-2.0 GHz DC-2.0 GHz	dB dB dB	— — —	— — —	$\pm(.5 + 5\%$ of atten setting) $\pm(.5 + 5\%$ of atten setting) $\pm(.7 + 7\%$ of atten setting)
VSWR	Full Range	DC-2.0 GHz	Ratio	—	1.5:1	1.8:1
Switching Speed	50% Cntl to 90%/10% RF 10% to 90% or 90% to 10%	— —	nS nS	— —	75 20	150 50
1 dB Compression	— —	50 MHz 0.5-2.0 GHz	dBm dBm	— —	+21 +24	— —
Input IP <sub>3</sub>	Two-tone inputs up to +5 dBm	50 MHz 0.5-2.0 GHz	dB dB	— —	+35 +48	— —
V <sub>CC</sub> <sup>1</sup> V <sub>EE</sub> <sup>1</sup>	— —	— —	V V	4.75 -8.0	5.0 -5.0	5.25 -4.75
V <sub>IL</sub> V <sub>IH</sub>	LOW-level input voltage HIGH-level input voltage	— —	V V	0.0 2.0	— —	0.8 5.0
I <sub>in</sub> (Input Leakage Current)	V <sub>in</sub> = V <sub>CC</sub> or GND	—	uA	-1.0	—	1.0
I <sub>CC</sub> (Quiescent Supply Current)	V <sub>cntrl</sub> = V <sub>CC</sub> or GND	—	uA	—	250	400
$\Delta I_{CC}^2$ (Additional Supply Current Per TTL Input Pin)	V <sub>CC</sub> = Max, V <sub>cntrl</sub> = V <sub>CC</sub> - 2.1 V	—	mA	—	—	1.0
I <sub>EE</sub>	V <sub>EE</sub> min to max, V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub>	—	mA	-1.0	-0.2	—
Thermal Resistance $\theta_{JA}$	PCB mount on FR4 material, copper trace, still air at +25°C	—	°C/W	—	90-130	—

1. Decoupling capacitors (.1  $\mu\text{F}$ ) are required on power supply lines.
2. For calculating  $\Delta I_{CC}$ , the number of TTL input pins is 6.

## Absolute Maximum Ratings<sup>3,4</sup>

Parameter	Absolute Maximum
Max. Input Power 0.05 GHz 0.5 - 2.0 GHz	+27 dBm +34 dBm
V <sub>CC</sub>	-0.5V $\leq$ V <sub>CC</sub> $\leq$ +7.0V
V <sub>EE</sub>	-8.5V $\leq$ V <sub>EE</sub> $\leq$ +0.5V
V <sub>CC</sub> - V <sub>EE</sub>	-0.5V $\leq$ V <sub>CC</sub> - V <sub>EE</sub> $\leq$ 14.5V
V <sub>in</sub> <sup>5</sup>	-0.5V $\leq$ V <sub>in</sub> $\leq$ V <sub>CC</sub> + 0.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

3. Exceeding any one or combination of these limits may cause permanent damage to this device.
4. M/A-COM does not recommend sustained operation near these survivability limits.
5. Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

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## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

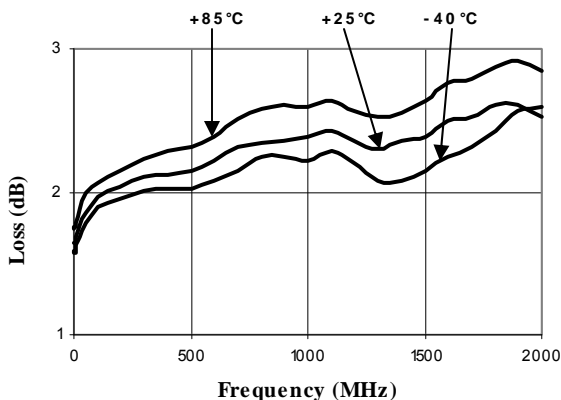
## Truth Table (Digital Attenuator)

C16	C8	C4	C2	C1	Attenuation
0	0	0	0	0	Loss, Reference
0	0	0	0	1	1.0 dB
0	0	0	1	0	2.0 dB
0	0	1	0	0	4.0 dB
0	1	0	0	0	8.0 dB
1	0	0	0	0	16.0 dB
1	1	1	1	1	31.0 dB

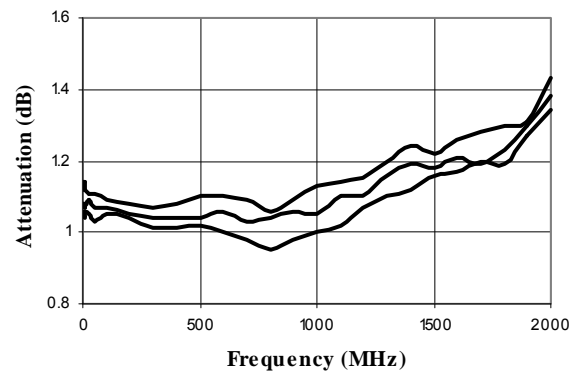
0 = TTL Low; 1 = TTL High

## Typical Performance Curves

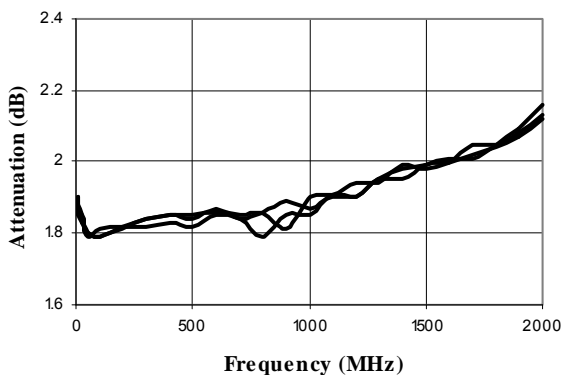
### Insertion Loss @ R, H & C



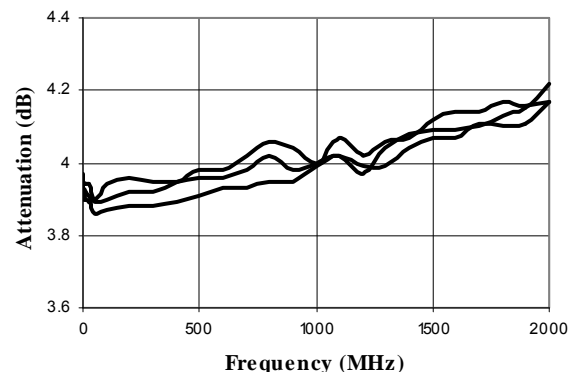
### 1 dB Bit @ R, H & C



### 2 dB Bit @ R, H & C

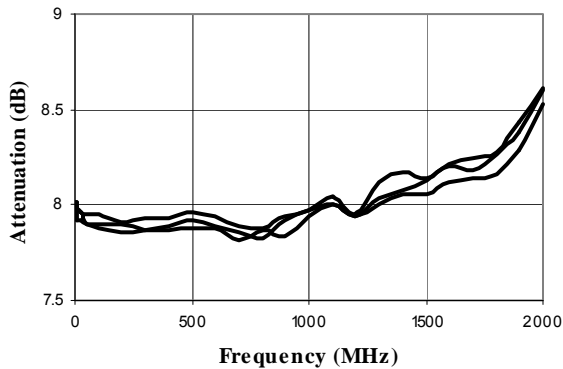


### 4 dB Bit @ R, H & C

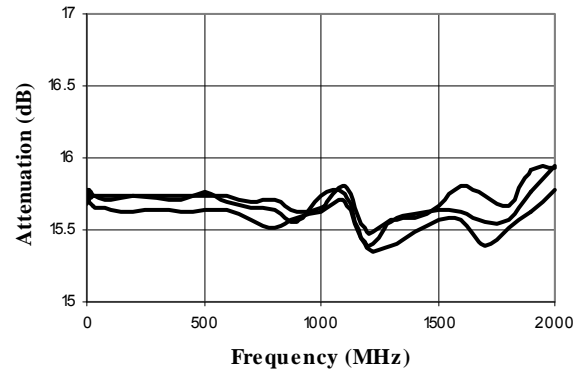


## Typical Performance Curves

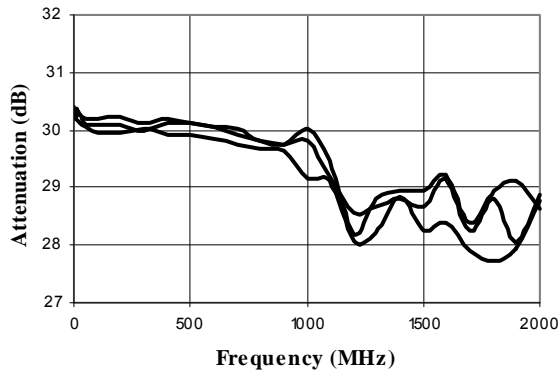
8 dB Bit @ R, H & C



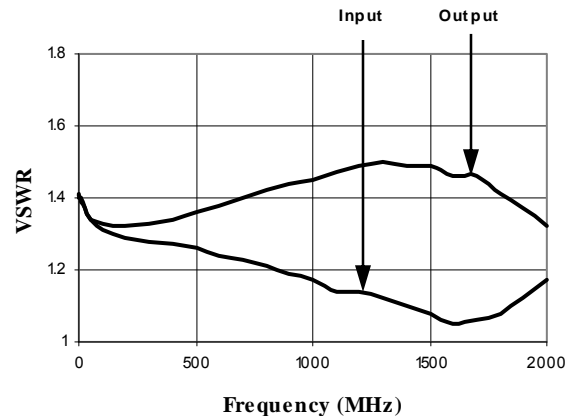
16 dB Bit @ R, H & C



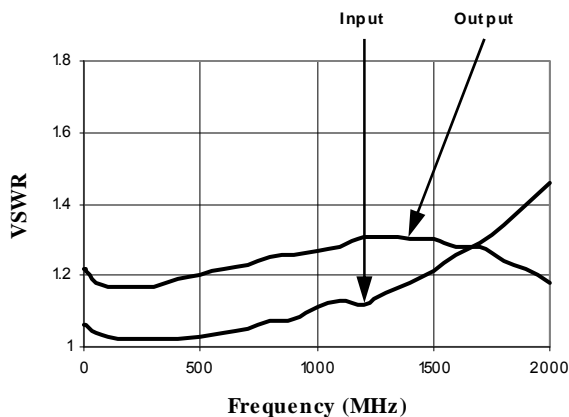
Max Attenuation @ R, H & C



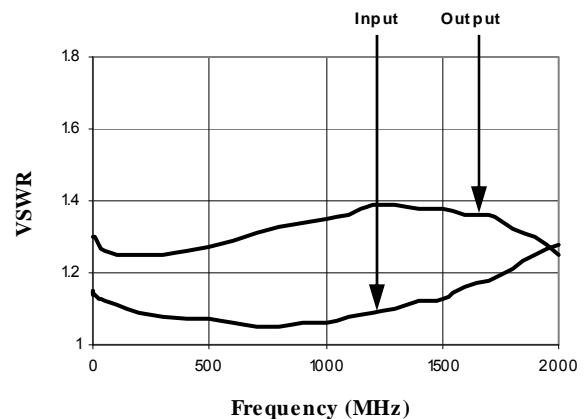
Maximum VSWR over Temp, Loss



Maximum VSWR over Temp, 1 dB Bit

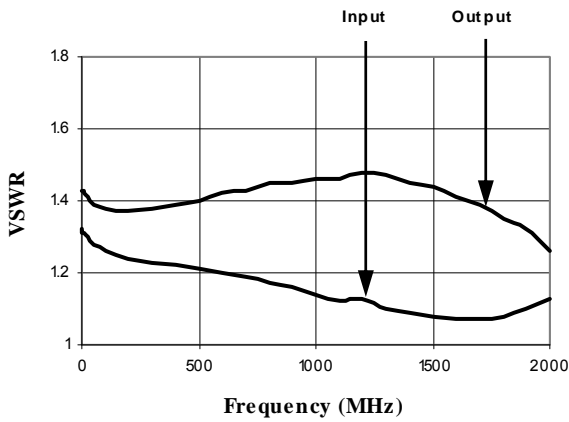


Maximum VSWR over Temp, 2 dB Bit

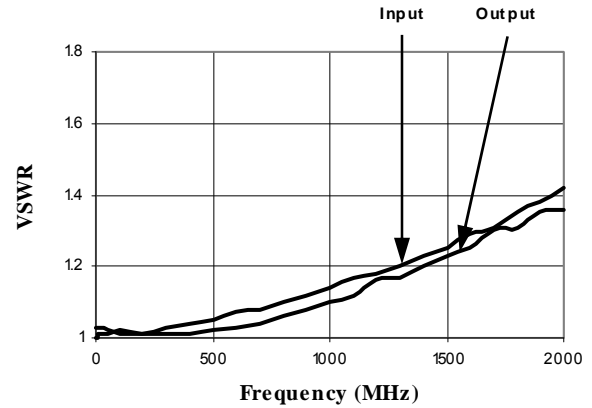


## Typical Performance Curves

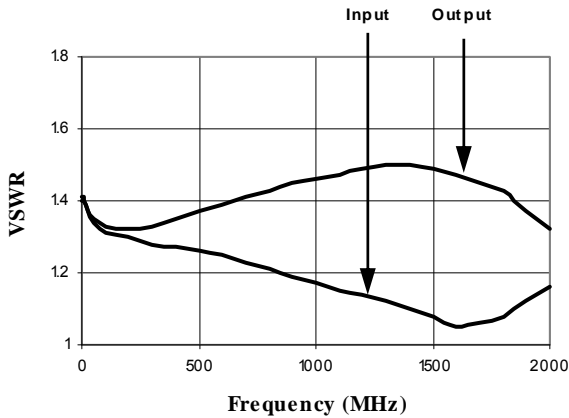
Maximum VSWR over Temp, 4 dB Bit



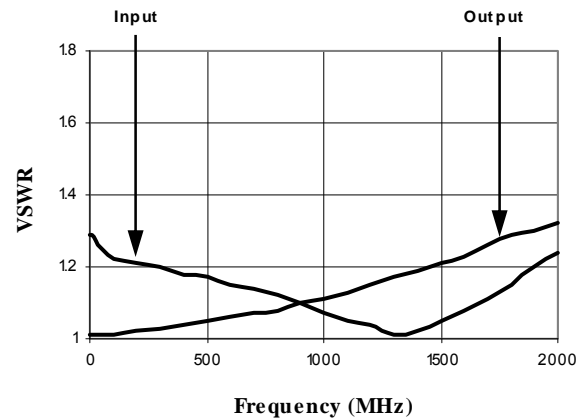
Maximum VSWR over Temp, 8 dB Bit



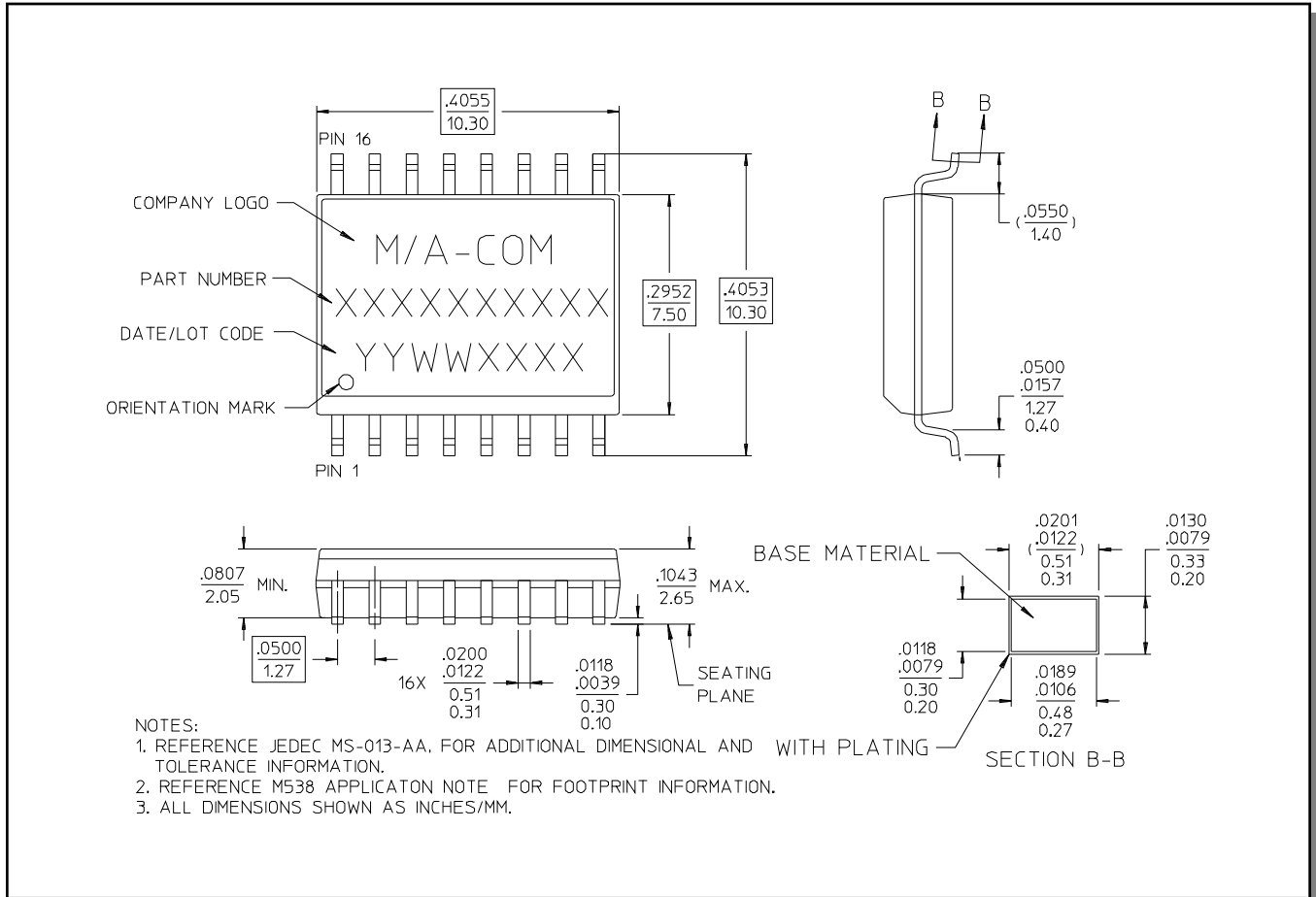
Maximum VSWR over Temp, 16 dB Bit



Maximum VSWR over Temp, Max Attenuation



## Lead-Free, SOW-16<sup>†</sup>



<sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.